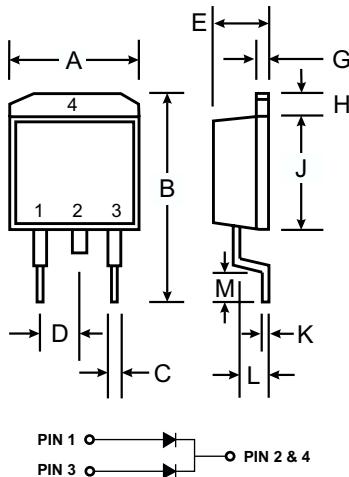


### Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 225A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Plastic Material: UL Flammability Classification Rating 94V-0

### Mechanical Data

- Case: D<sup>2</sup>PAK Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Marking: Type Number
- Weight: 1.7 grams (approx.)
- Mounting Position: Any



D <sup>2</sup> PAK		
Dim	Min	Max
A	9.65	10.69
B	14.60	15.88
C	0.51	1.14
D	2.29	2.79
E	4.37	4.83
G	1.14	1.40
H	1.14	1.40
J	8.25	9.25
K	0.30	0.64
L	2.03	2.92
M	2.29	2.79

All Dimensions in mm

### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	SBG 2030CT	SBG 2035CT	SBG 2040CT	SBG 2045CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RMM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	35	40	45	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	21	25	28	32	V
Average Rectified Output Current @ T <sub>C</sub> = 105°C	I <sub>O</sub>		20			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>			225		A
Forward Voltage, per Element @ I <sub>F</sub> = 10A	V <sub>FM</sub>		0.55			V
Peak Reverse Current @ T <sub>j</sub> = 25°C at Rated DC Blocking Voltage @ T <sub>j</sub> = 100°C	I <sub>RM</sub>		1.0 50			mA
Typical Junction Capacitance (Note 2)	C <sub>j</sub>		650			pF
Typical Thermal Resistance Junction to Case (Note 1)	R <sub>θJC</sub>		2.0			K/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>		-65 to +125			°C

Notes: 1. Thermal resistance: junction to case mounted on heat sink.  
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

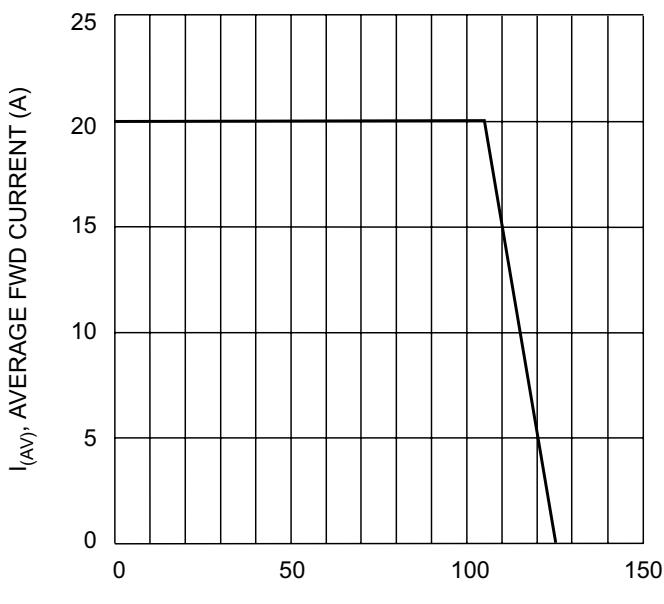


Fig. 1 Forward Current Derating Curve

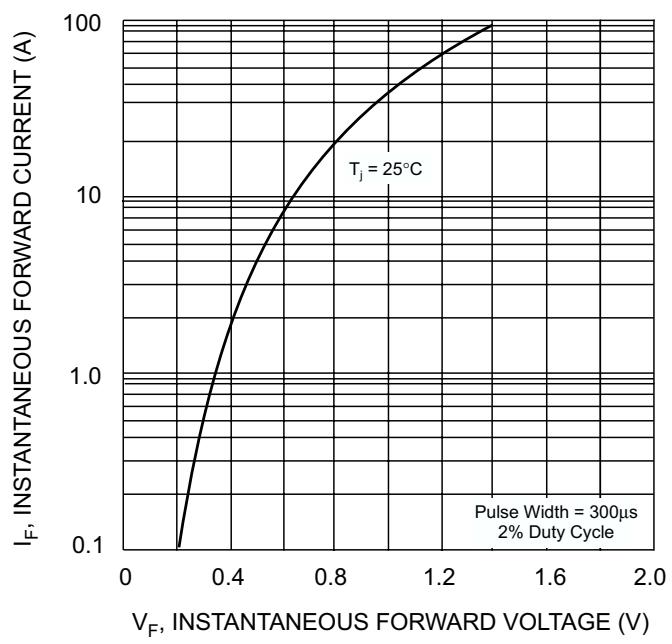


Fig. 2 Typical Forward Characteristics

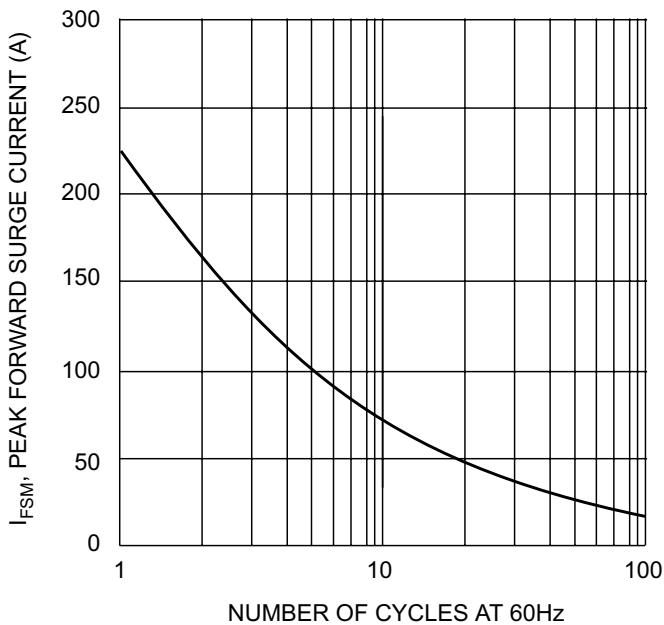


Fig. 3 Max Non-Repetitive Surge Current

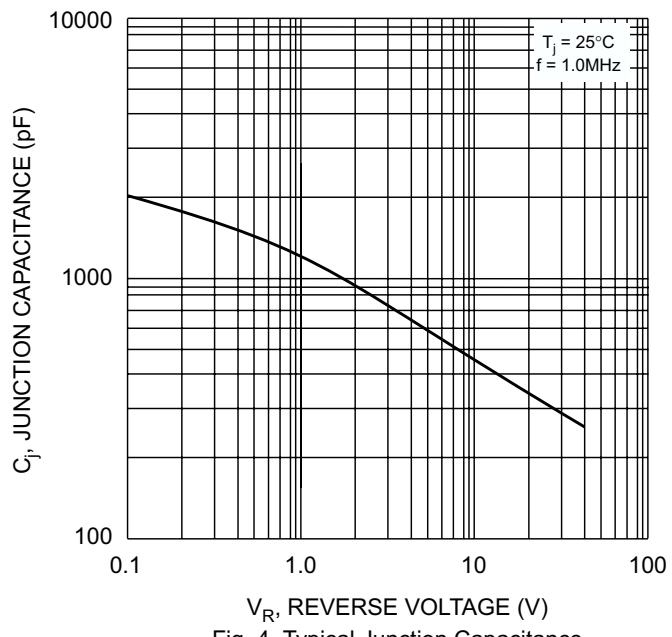


Fig. 4 Typical Junction Capacitance